300V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

Features

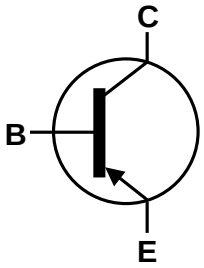
- BV_{CEO} > -300V
- I_C = -1A High Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)}$ < -240mV @ -1A
- h_{FE} Specified up to -2A for a High Gain Hold-Up
- Complementary NPN Type: FZT857Q
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The FZT957Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

Mechanical Data

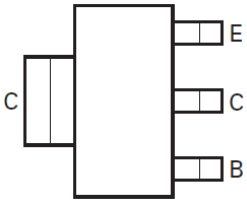
- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

SOT223 (Type DN)

Top View



Device Symbol



Top View
Pin-Out

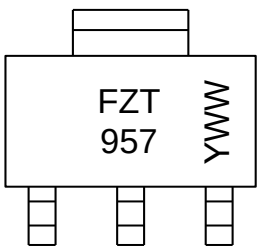
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (Inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
FZT957QTA	SOT223 (Type DN)	FZT957	7	12	1,000	Reel
FZT957QTC	SOT223 (Type DN)	FZT957	13	12	4,000	Reel

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/.

Marking Information

SOT223



FZT 957 = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 3 = 2023)
WW or $\overline{WW}$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-330	V
Collector-Emitter Voltage	V_{CEO}	-300	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-1	A
Peak Pulse Current	I_{CM}	-2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

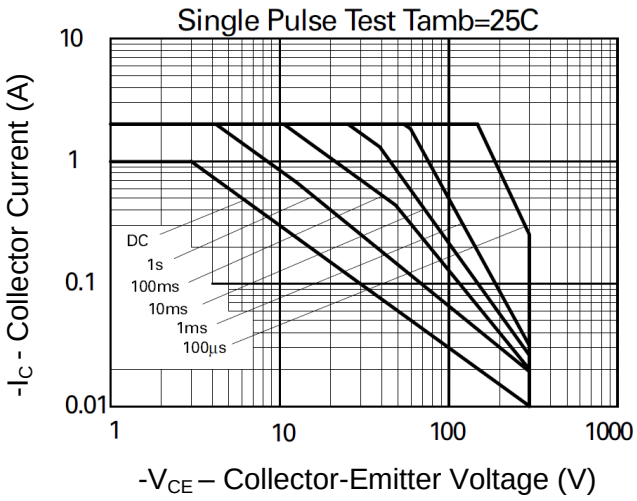
Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 5)	P_D	3 24	W mW /°C
	(Note 6)		1.6 12.8	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	42	°C/W
	(Note 6)	$R_{\theta JA}$	78	
Thermal Resistance Junction to Lead	(Note 7)	$R_{\theta JL}$	8.8	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

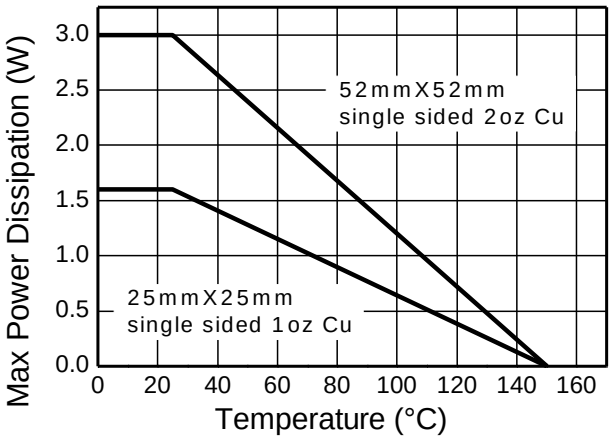
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

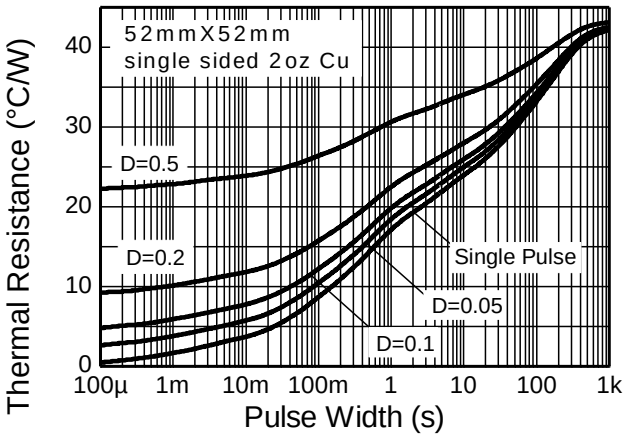
Thermal Characteristics and Derating Information



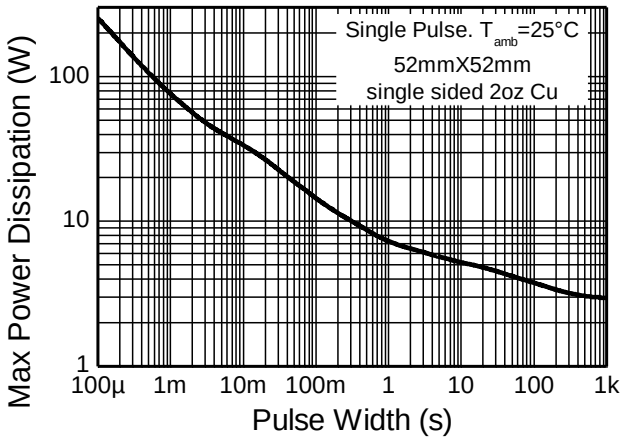
Safe Operating Area



Derating Curve



Transient Thermal Impedance



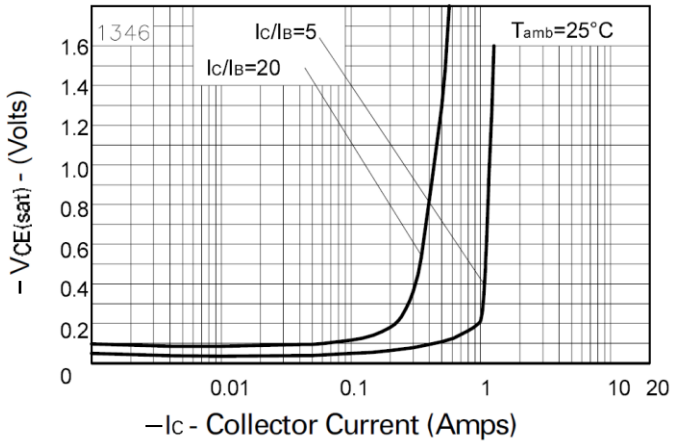
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

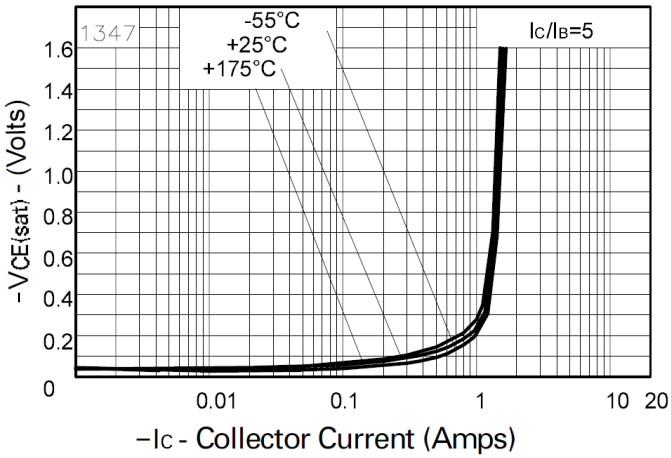
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-330	-440	—	V	I_C = -100µA
Collector-Emitter Breakdown Voltage	BV_{CER}	-330	-440	—	V	I_C = -1µA, R_B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-300	-400	—	V	I_C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8	—	V	I_E = -100µA
Collector Cut-Off Current	I_{CBO}	— —	— —	-50 -1	nA µA	V_{CB} = -300V; R ≤1kΩ V_{CB} = -300V, T_A = +100°C
Collector Cut-Off Current	I_{CER}	— —	— —	-50 -1	nA µA	V_{CE} = -300V V_{CE} = -300V, T_A = +100°C
Emitter Cut-Off Current	I_{EBO}	—	—	-10	nA	V_{EB} = -6V
DC Current Transfer Static Ratio (Note 9)	h_{FE}	100	200	-	—	I_C = -10mA, V_{CE} = -10V
		100	200	300		I_C = -0.5A, V_{CE} = -10V
		90	170	—		I_C = -1A, V_{CE} = -10V
		—	10	—		I_C = -2A, V_{CE} = -10V
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	-60	-100	mV	I_C = -100mA, I_B = -10mA
		—	-110	-165		I_C = -500mA, I_B = -100mA
		—	-170	-240		I_C = -1A, I_B = -300mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	-910	-1,150	mV	I_C = -1A, I_B = -300mA
Base-Emitter Turn-on Voltage (Note 9)	$V_{BE(on)}$	—	-750	-1,020	mV	I_C = -1A, V_{CE} = -10V
Transitional Frequency	f_T	—	85	—	MHz	I_C = -100mA, V_{CE} = -10V, f = 50MHz
Output Capacitance	C_{obo}	—	23	—	pF	V_{CB} = -20V, f = 1MHz
Switching Time	t_{on}	—	108	—	ns	V_{CC} = -100V, I_C = -500mA, $-I_{B1}$ = I_{B2} = -50mA
	t_{off}	—	2,500	—		

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

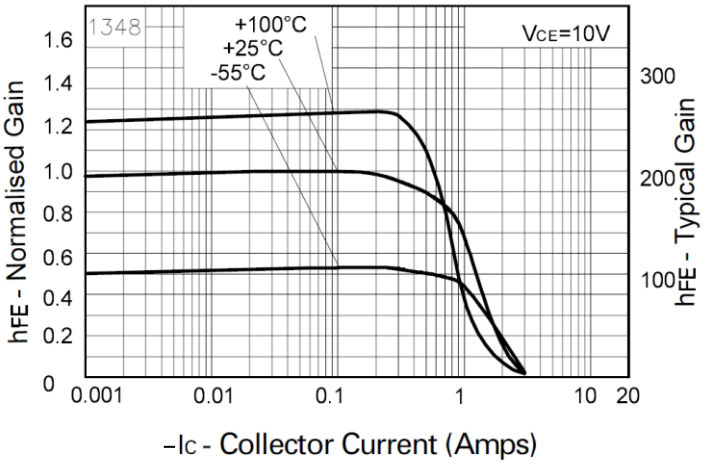
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



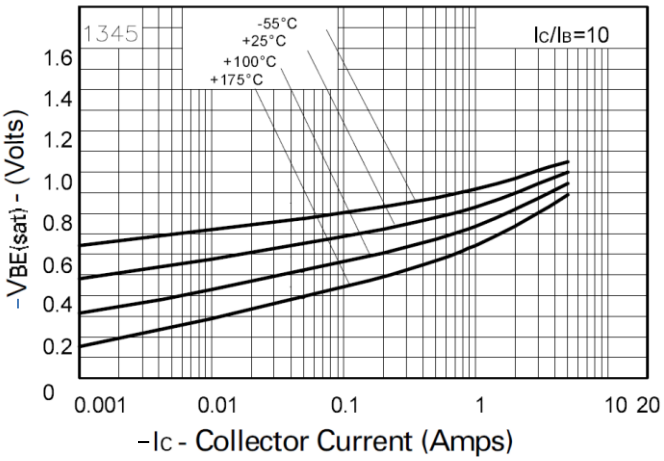
VCE(sat) v IC



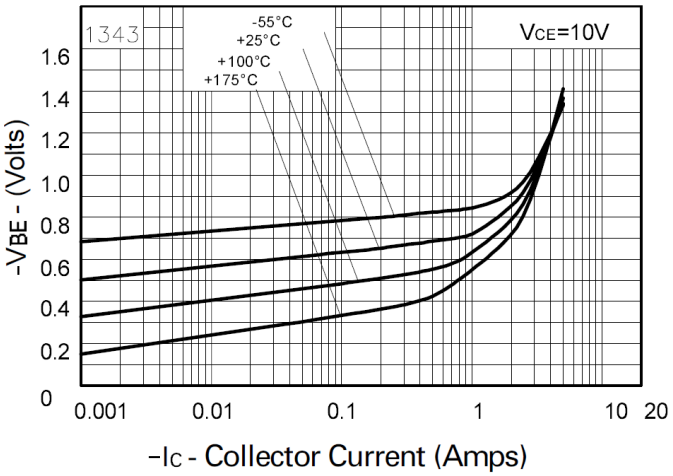
VCE(sat) v IC



hFE v IC



VBE(sat) v IC

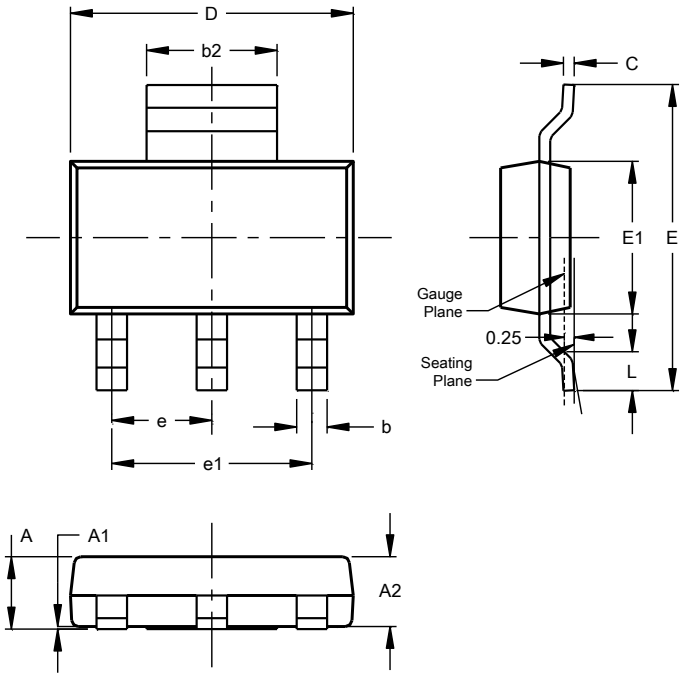


VBE(on) v IC

Package Outline Dimensions

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

SOT223 (Type DN)



SOT223 (Type DN)			
Dim	**Min**	**Max**	**Typ**
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

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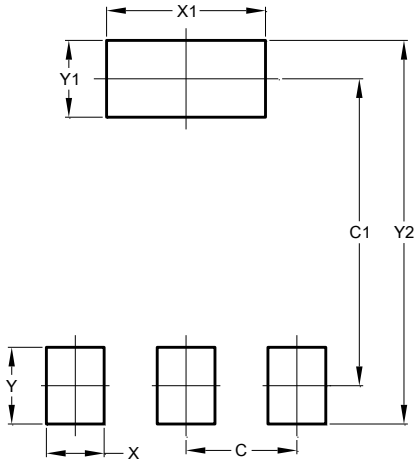
SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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